

APT40GP90B2DQ2G

APT40GP90B2DQ2G Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



APT40GP90B2DQ2G Specifications

Manufacturer Part Number	APT40GP90B2DQ2G
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-247-3 Variant
Series	POWER MOS 7?
IGBT Type	PT
Voltage - Collector Emitter Breakdown (Max)	900V
Current - Collector (Ic) (Max)	101A
Current - Collector Pulsed (Icm)	160A
Vce(on) (Max) @ Vge, Ic	3.9V @ 15V, 40A
Power - Max	543W
Switching Energy	795µJ (off)
Input Type	Standard
Gate Charge	145nC
Td (on/off) @ 25°C	14ns/90ns
Test Condition	600V, 40A, 4.3 Ohm, 15V
Reverse Recovery Time (trr)	-
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-247-3 Variant
Supplier Device Package	-
	Report errors?

APT40GP90B2DQ2G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

APT40GP90B2DQ2G Payment Methods



If you have any question about APT40GP90B2DQ2G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com